

SPECIFICATION

Device Name : IGBT Module

Type Name : 7MBR10SA120D-01

Spec. No. : MS6M 0545

Date : Jun. - 02 - 2000

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Matsumoto Factory

	DATE	NAME	APPROVED	Fuji Electric Co., Ltd.		
DRAWN	Jun. - 2 - '00	<i>T. Kobayashi</i>		DWG. NO.	MS6M 0545	1 / 10
CHECKED	June - 2 - 00	<i>S. Matsumoto</i>	<i>T. Kobayashi</i>			

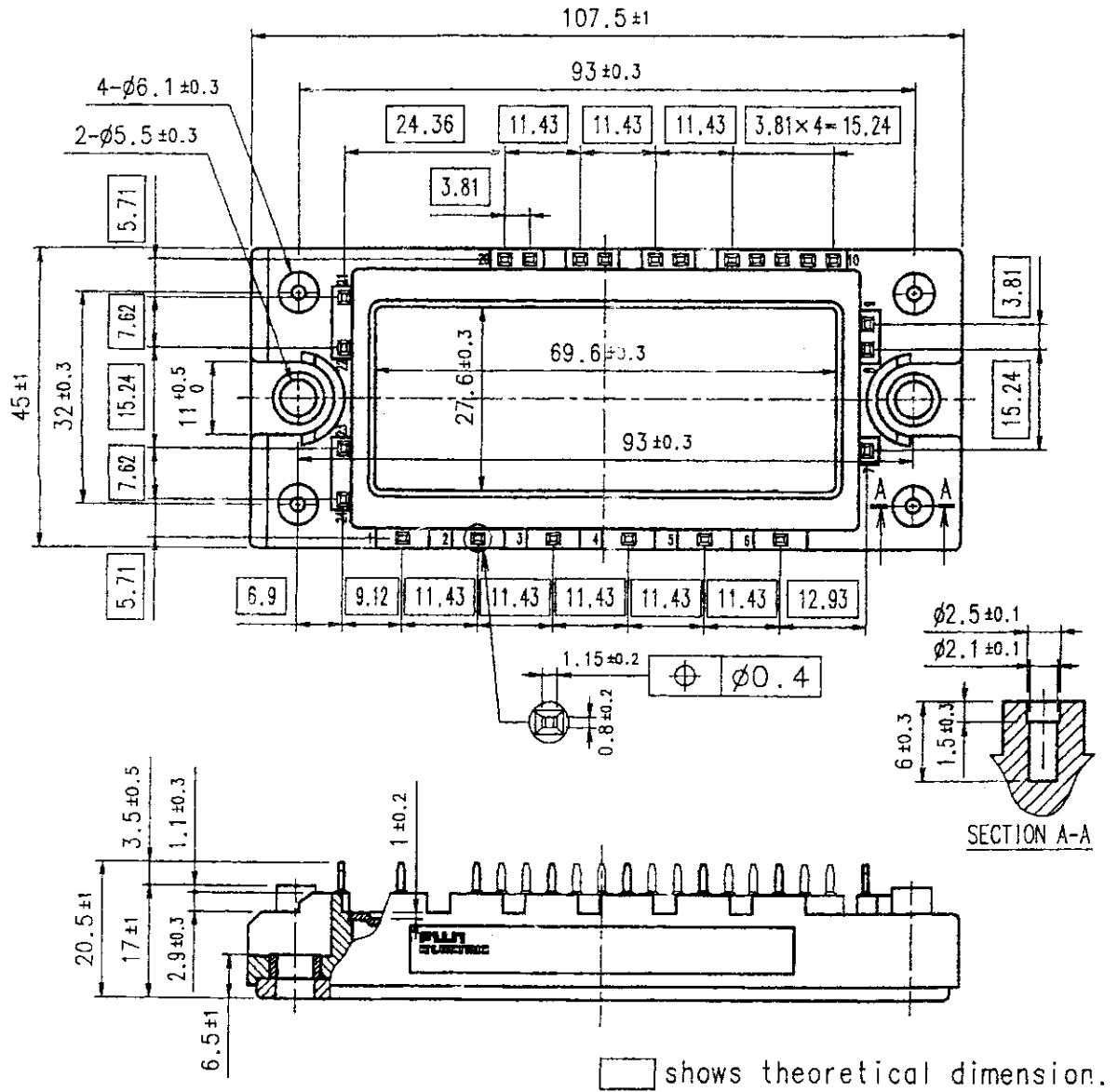
Revised Records

Date	Classi- fication	Ind.	Content	Applied date	Drawn	Checked	Approved
Jan-2-60	enactment	—	—	Issued date	—	S. N. A. A.	T. Miyazaki

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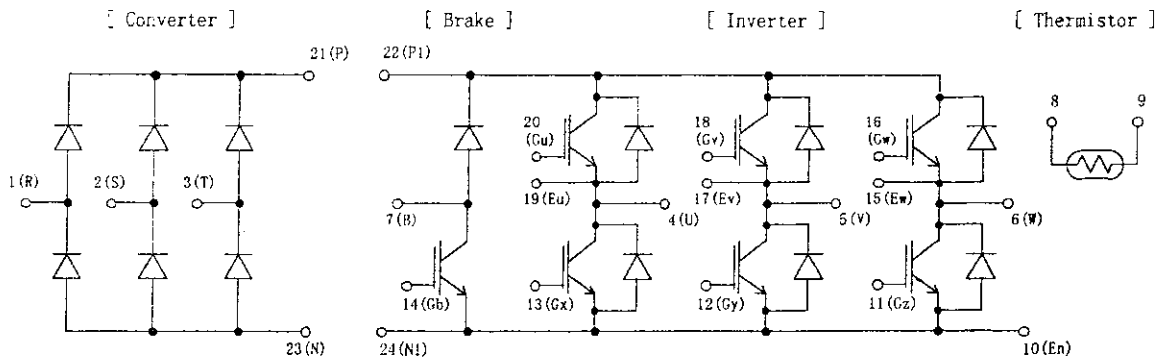
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1. Outline Drawing (Unit : mm)



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2. Equivalent circuit



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3. Absolute Maximum Ratings (at Tc= 25C unless otherwise specified)

Items		Symbols	Conditions	Maximum Ratings	Units	
Inverter	Collector-Emitter voltage	VCES		1200	V	
	Gate-Emitter voltage	VGES		+20	V	
	Collector current	Ic	Continuous	Tc=25C	15	A
				Tc=80C	10	
		Icp	1ms	Tc=25C	30	A
				Tc=80C	20	
	-Ic			10	A	
Collector Power Dissipation	Pc	1 device		75	W	
Brake	Collector-Emitter voltage	VCES		1200	V	
	Gate-Emitter voltage	VGES		+20	V	
	Collector current	Ic	Continuous	Tc=25C	15	A
				Tc=80C	10	
		Icp	1ms	Tc=25C	30	A
				Tc=80C	20	
Collector Power Dissipation	Pc	1 device		75	W	
Repetitive peak reverse Voltage(Diode)	VRRM			1200	V	
Converter	Repetitive peak reverse Voltage	VRRM		1600	V	
	Average Output Current	Io	50Hz/60Hz sine wave	25	A	
	Surge Current (Non-Repetitive)	IFSM	Tj=150C,10ms	260	A	
	I ² t (Non-Repetitive)	I ² t	half sine wave	338	A ² s	
Junction temperature	Tj			150	C	
Storage temperature	Tstg			-40~ +125	C	
Isolation voltage	between terminal and copper base ^{(*)1}	Viso	AC : 1min.	2500	V	
	between thermistor and others ^{(*)2}			2500	V	
Mounting Screw Torque ^{(*)3}				3.5	Nm	

(*)1 All terminals should be connected together when isolation test will be done.

(*)2 Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(*)3 Recommendable Value : 2.5~3.5 Nm (M5)

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4. Electrical characteristics (at T_j= 25C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units		
			min.	typ.	Max.			
Inverter	Zero gate voltage Collector current	ICES	VGE 0 V, VCE 1200 V			1.0	mA	
	Gate-Emitter leakage current	IGES	VCE 0 V, VGE +-20 V			200	nA	
	Gate-Emitter threshold voltage	VGE(th)	VCE 20 V, I _c = 10 mA	5.5	7.2	8.5	V	
	Collector-Emitter saturation voltage	VCE(sat)	VGE 15 V, I _c = 10 A	chip	2.1			V
			terminal		2.15	2.6		
	Input capacitance	Cies	VGE 0 V, VCE 10 V f = 1 MHz		1200		pF	
	Turn-on time	ton	Vcc= 600 V		0.35	1.2	us	
		tr	I _c = 10 A		0.25	0.6		
		tr(η)	VGE +-15 V		0.1			
	Turn-off time	toff	RG = 120 ohm		0.45	1.0	us	
tf				0.08	0.3			
Forward on voltage	VF	IF = 10 A	chip	2.3		V		
			terminal	2.35	3.2			
Reverse recovery time	trr	IF = 10 A			350	ns		
Brake	Zero gate voltage Collector current	ICES	VGE 0 V, VCE 1200 V			1.0	mA	
	Gate-Emitter leakage current	IGES	VCE 0 V, VGE +-20 V			200	nA	
	Collector-Emitter saturation voltage	VCE(sat)	VGE 15 V, I _c = 10 A	chip	2.1		V	
			terminal		2.2	2.6		
	Turn-on time	ton	Vcc= 600 V		0.35	1.2	us	
		tr	I _c = 10 A		0.25	0.6		
		toff	VGE +-15 V		0.45	1.0		
	Turn-off time	toff	RG = 120 ohm		0.08	0.3	us	
		tf						
	Reverse current	IRRM	VR = 1200 V			1.0	mA	
Converter	Forward on voltage	VFM	IF = 10 A	chip	0.9		V	
				terminal	1.0	1.5		
Reverse current	IRRM	VR = 1600 V			1.0	mA		
Thermistor	Resistance	R	T = 25C	5000		ohm		
			T = 100C	465	495	520		
	B value	B	T = 25/50C	3305	3375	3450	K	

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5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			1.67	C/W
		Inverter FWD			2.78	
		Brake IGBT			1.67	
		Converter Diode			1.30	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound (*)		0.05		C/W

* This is the value which is defined mounting on the additional cooling fin with thermal compound.

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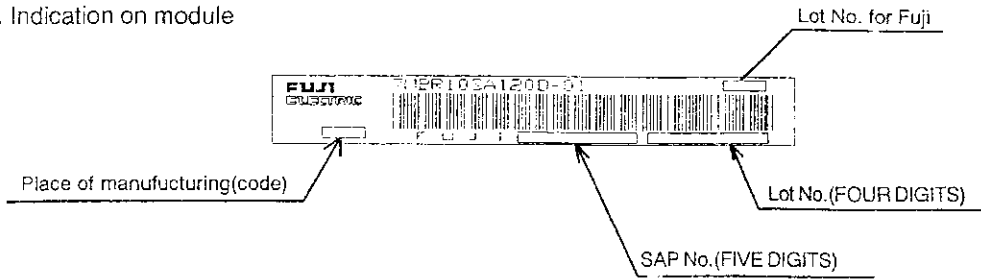
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6. Indication on module



7. Applicable category

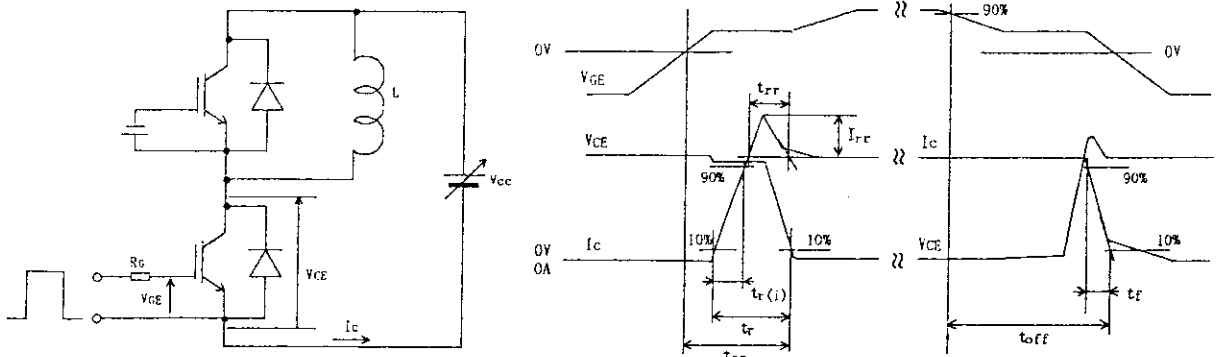
This specification is applied to Power Integrated Module named 7MBR10SA120D-01 .

8. Storage and transportation notes

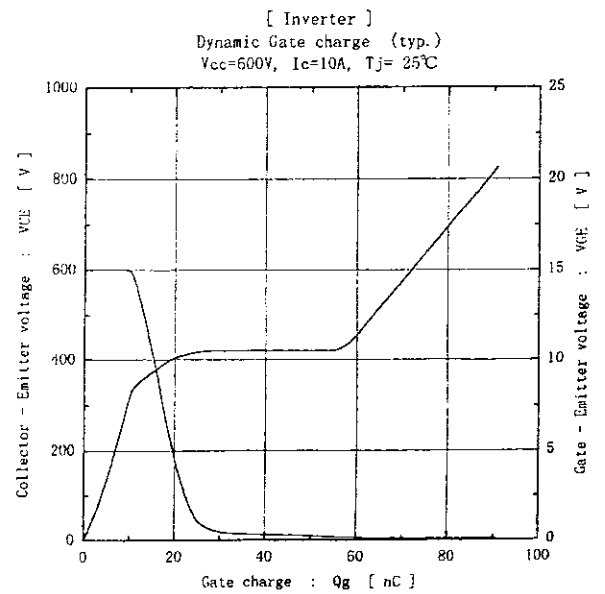
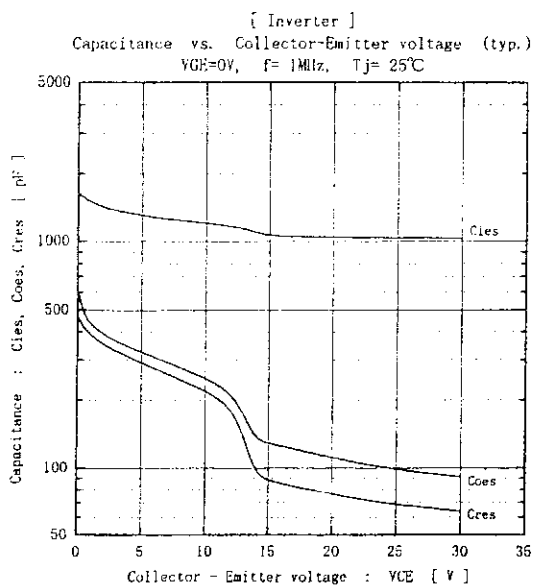
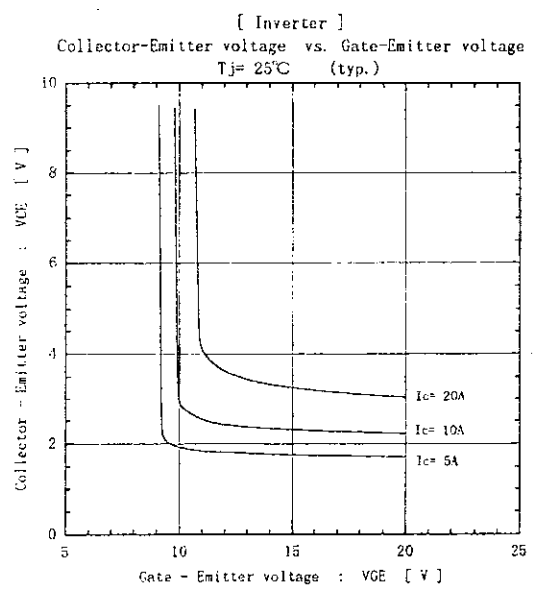
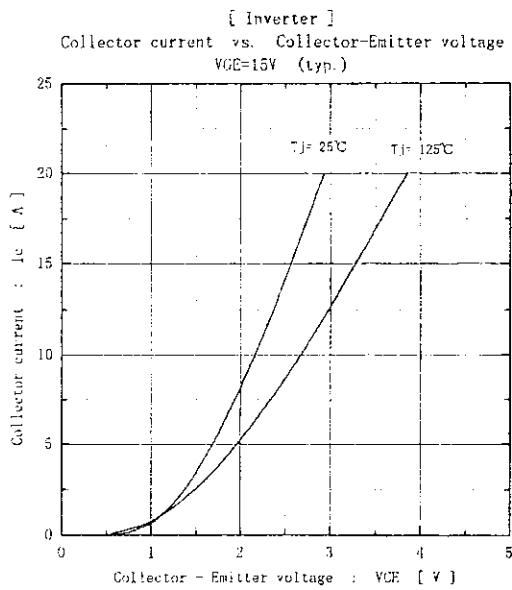
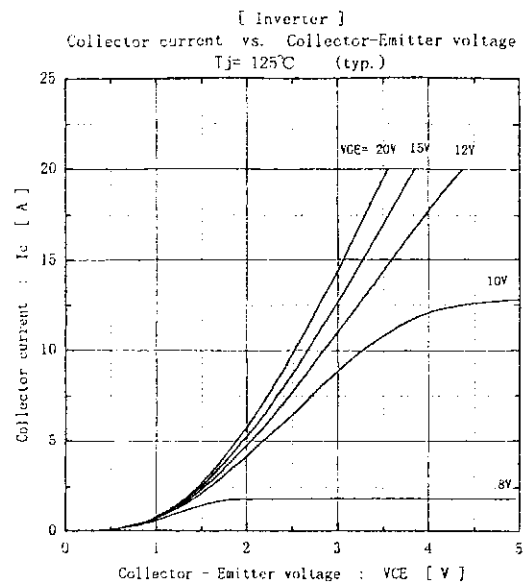
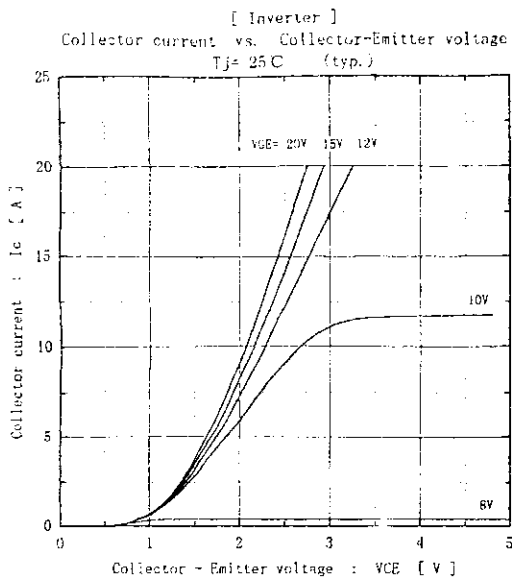
- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75% .
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.
- Please connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction.

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9. Definitions of switching time



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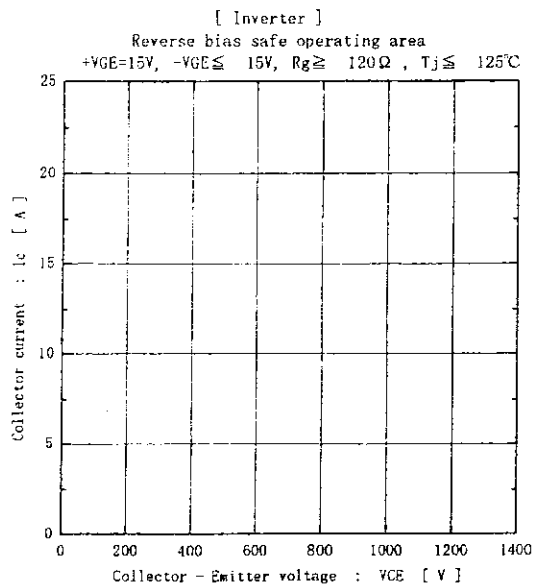
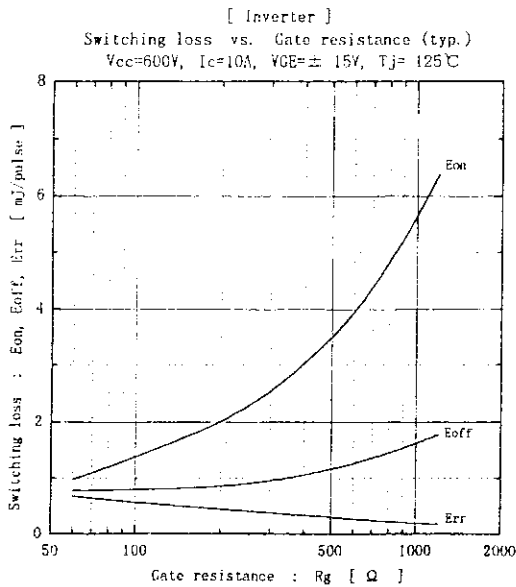
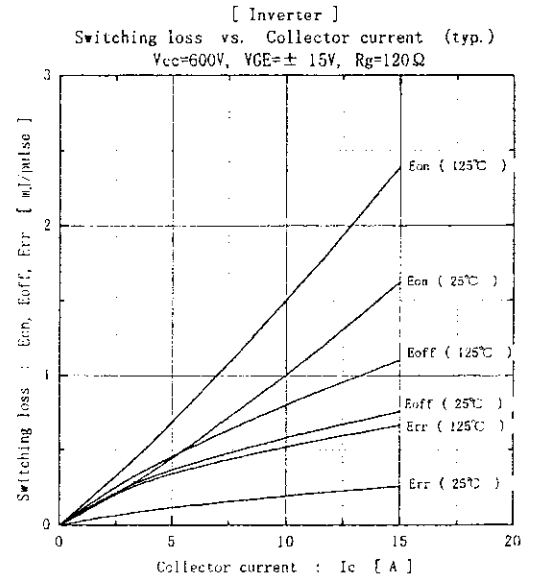
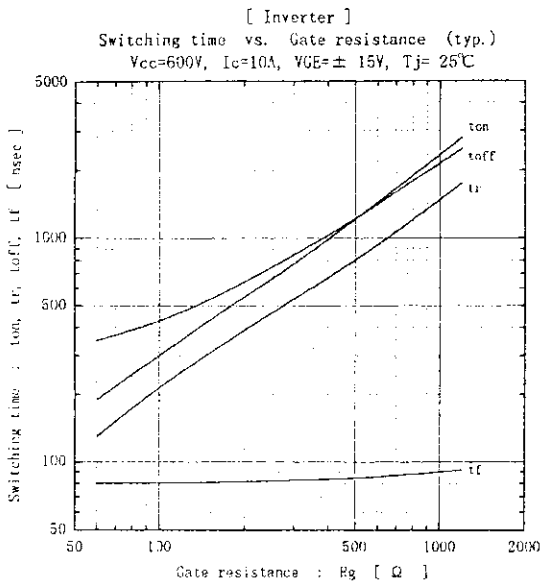
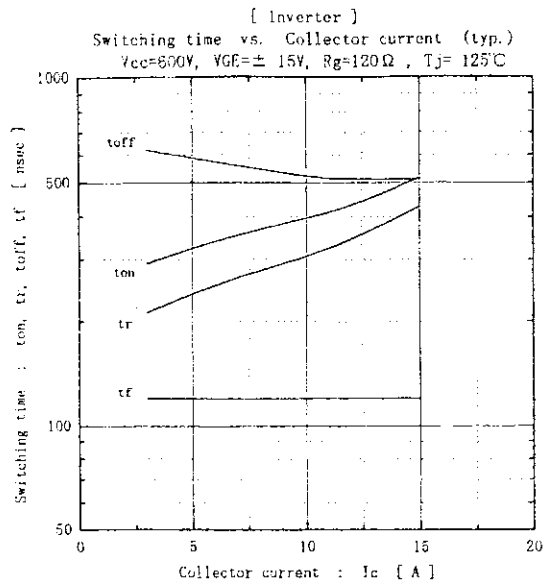
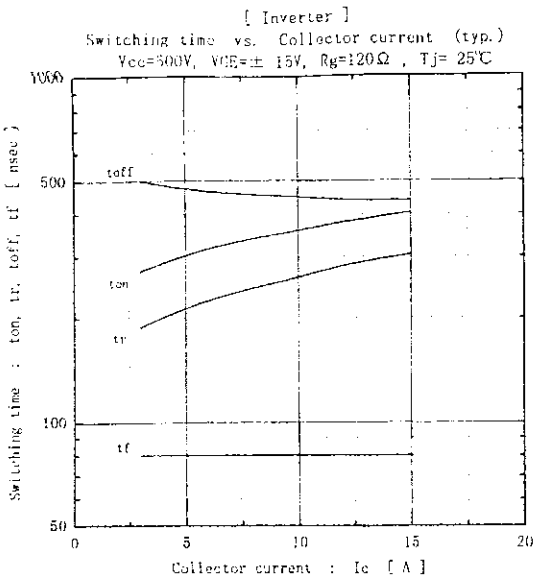
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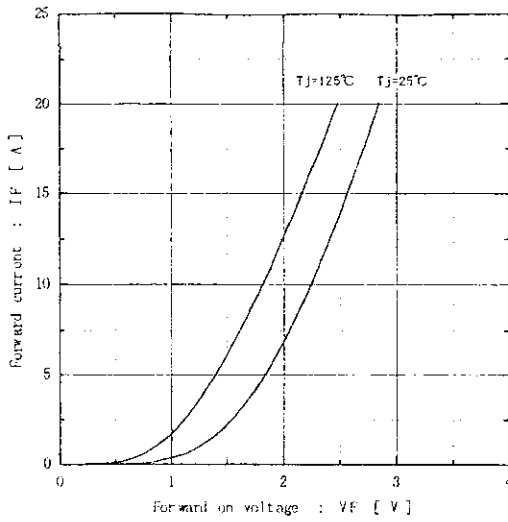
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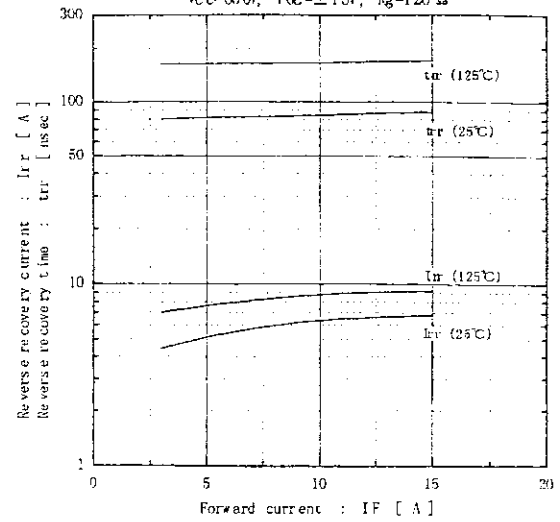
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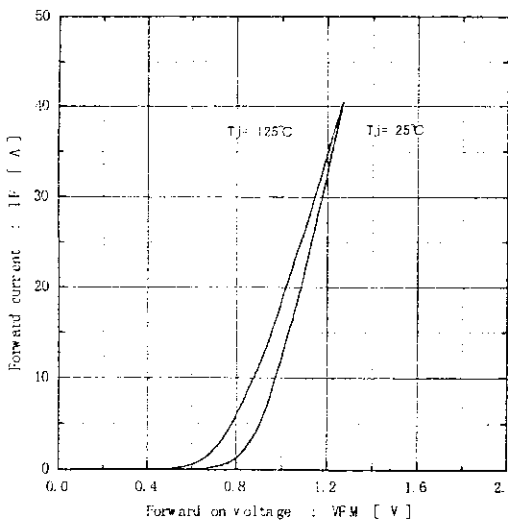
[Inverter]
Forward current vs. Forward on voltage (typ.)



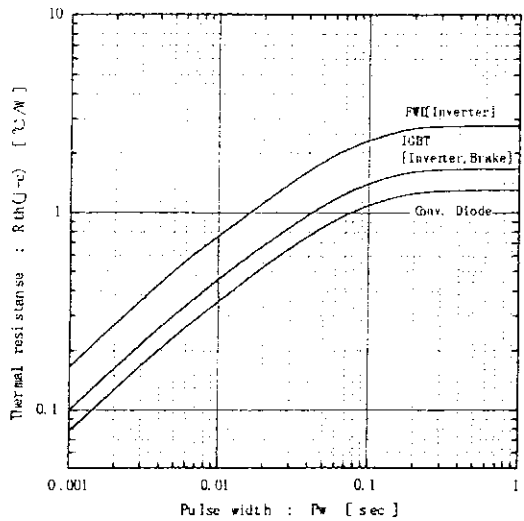
[Inverter]
Reverse recovery characteristics (typ.)
V_{CE}=60V, V_{CE}=±15V, R_g=12Ω



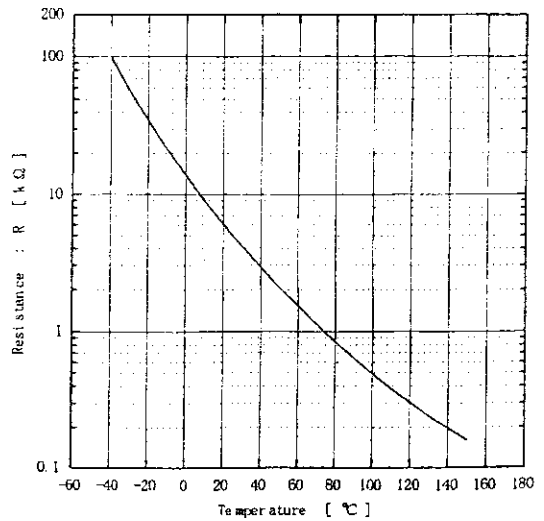
[Converter]
Forward current vs. Forward on voltage (typ.)



Transient thermal resistance



[Thermistor]
Temperature characteristic (typ.)



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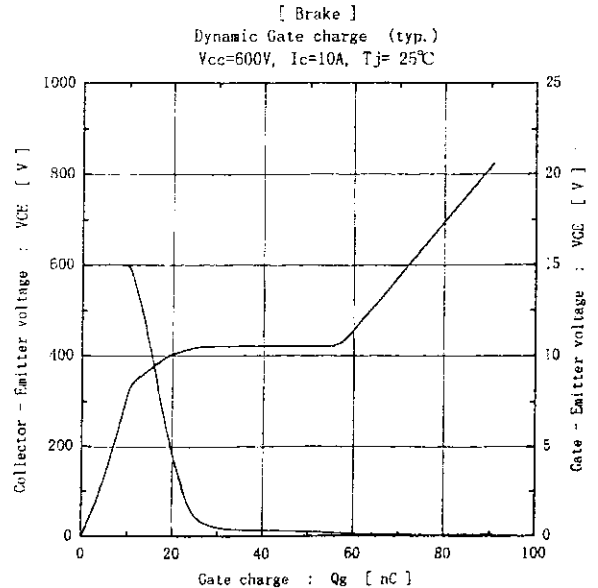
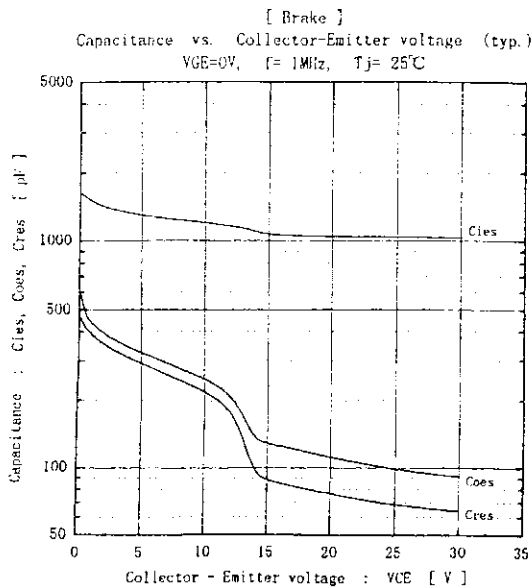
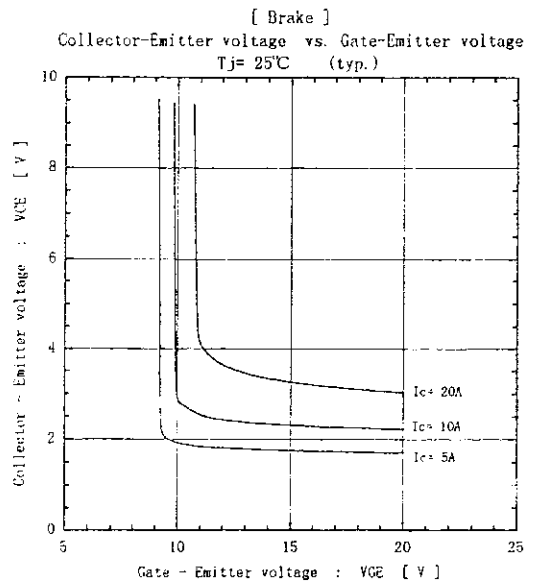
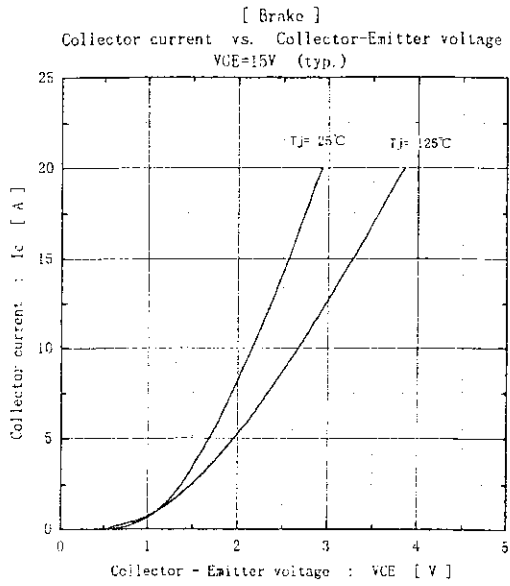
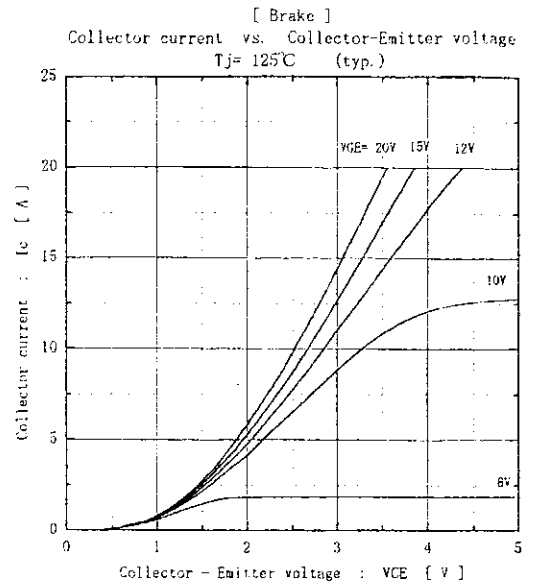
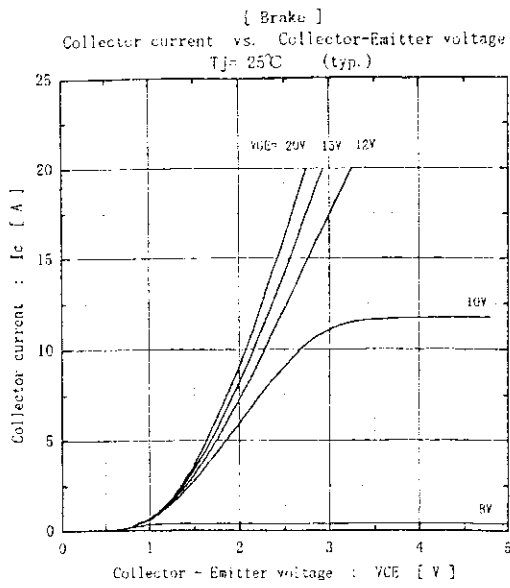
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